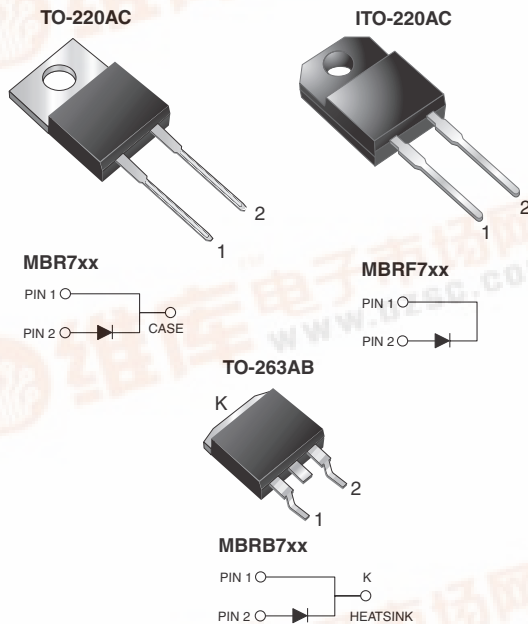


## Schottky Barrier Rectifier



### FEATURES

- Guardring for overvoltage protection
- Lower power losses, high efficiency
- Low forward voltage drop
- High forward surge capability
- High frequency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C (for TO-263AB package)
- Solder dip 260 °C, 40 s (for TO-220AC and ITO-220AC package)
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC


**RoHS**  
COMPLIANT

### TYPICAL APPLICATIONS

For use in low voltage, high frequency rectifier of switching mode power supplies, freewheeling diodes, dc-to-dc converters or polarity protection application.

### MECHANICAL DATA

**Case:** TO-220AC, ITO-220AC, TO-263AB

Epoxy meets UL 94V-0 flammability rating

**Terminals:** Matte tin plated leads, solderable per J-STD-002 and JESD22-B102

E3 suffix for consumer grade, meets JESD 201 class 1A whisker test, HE3 suffix for high reliability grade (AEC Q101 qualified), meets JESD 201 class 2 whisker test

**Polarity:** As marked

**Mounting Torque:** 10 in-lbs maximum

### PRIMARY CHARACTERISTICS

$I_{F(AV)}$	7.5 A
$V_{RRM}$	35 V to 60 V
$I_{FSM}$	150 A
$V_F$	0.57 V, 0.65 V
$T_J \text{ max.}$	150 °C

### MAXIMUM RATINGS ( $T_C = 25\text{ °C}$ unless otherwise noted)

PARAMETER	SYMBOL	MBR735	MBR745	MBR750	MBR760	UNIT
Maximum repetitive peak reverse voltage	$V_{RRM}$	35	45	50	60	V
Working peak reverse voltage	$V_{RWM}$	35	45	50	60	V
Maximum DC blocking voltage	$V_{DC}$	35	45	50	60	V
Maximum average forward rectified current (Fig. 1)	$I_{F(AV)}$	7.5				A
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load	$I_{FSM}$	150				A
Peak repetitive reverse current at $t_p = 2.0\ \mu\text{s}$ , 1 kHz	$I_{RRM}$	1.0		0.5		A
Voltage rate of change (rated $V_R$ )	$dV/dt$	10 000				V/ $\mu\text{s}$
Operating junction temperature range	$T_J$	- 65 to + 150				°C
Storage temperature range	$T_{STG}$	- 65 to + 175				°C
Isolation voltage (ITO-220AC only) from terminal to heatsink $t = 1\ \text{min}$	$V_{AC}$	1500				V

# MBR(F,B)735 thru MBR(F,B)760



Vishay General Semiconductor

ELECTRICAL CHARACTERISTICS (T <sub>C</sub> = 25 °C unless otherwise noted)								
PARAMETER	TEST CONDITIONS		SYMBOL	MBR735	MBR745	MBR750	MBR760	UNIT
Maximum instantaneous forward voltage <sup>(1)</sup>	I <sub>F</sub> = 7.5 A	T <sub>C</sub> = 25 °C	V <sub>F</sub>	-	-	0.75	-	V
	I <sub>F</sub> = 7.5 A	T <sub>C</sub> = 125 °C		0.57	-	0.65	-	
	I <sub>F</sub> = 15 A	T <sub>C</sub> = 25 °C		0.84	-	-	-	
	I <sub>F</sub> = 15 A	T <sub>C</sub> = 125 °C		0.72	-	-	-	
Maximum reverse current at DC blocking voltage		T <sub>C</sub> = 25 °C T <sub>C</sub> = 125 °C	I <sub>R</sub>	0.1 15		0.5 50		mA

**Note:**

(1) Pulse test: 300 μs pulse width, 1 % duty cycle

THERMAL CHARACTERISTICS (T <sub>C</sub> = 25 °C unless otherwise noted)					
PARAMETER	SYMBOL	MBR	MBRF	MBRB	UNIT
Thermal resistance from junction to case	R <sub>θJC</sub>	3.0	5.0	3.0	°C/W

ORDERING INFORMATION (Example)					
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE
TO-220AC	MBR745-E3/45	1.80	45	50/tube	Tube
ITO-220AC	MBRF745-E3/45	1.94	45	50/Tube	Tube
TO-263AB	MBRB745-E3/45	1.33	45	50/Tube	Tube
TO-263AB	MBRB745-E3/81	1.33	81	800/reel	Tape reel
TO-220AC	MBR745HE3/45 <sup>(1)</sup>	1.80	45	50/tube	Tube
ITO-220AC	MBRF745HE3/45 <sup>(1)</sup>	1.94	45	50/Tube	Tube
TO-263AB	MBRB745HE3/45 <sup>(1)</sup>	1.33	45	50/Tube	Tube
TO-263AB	MBRB745HE3/81 <sup>(1)</sup>	1.33	81	800/reel	Tape reel

**Note:**

(1) Automotive grade AEC Q101 qualified

## RATINGS AND CHARACTERISTICS CURVES

(T<sub>A</sub> = 25 °C unless otherwise noted)

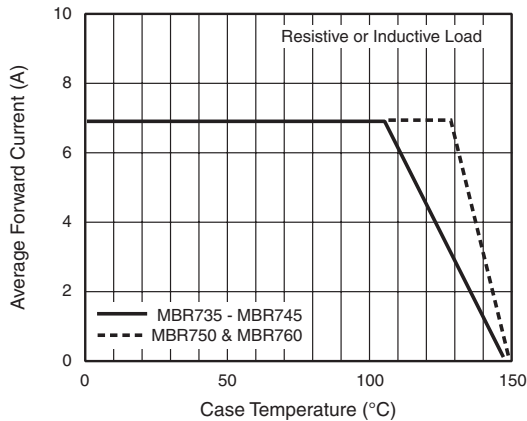


Figure 1. Forward Current Derating Curve

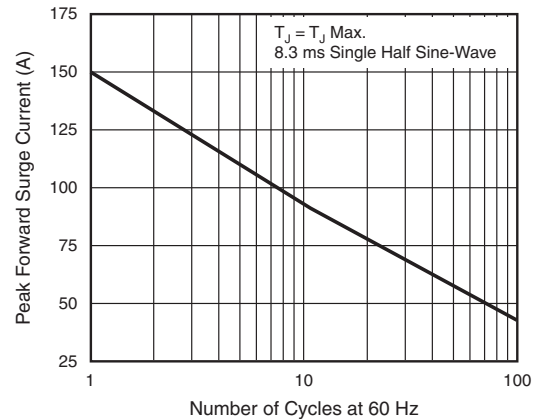


Figure 2. Maximum Non-Repetitive Peak Forward Surge Current

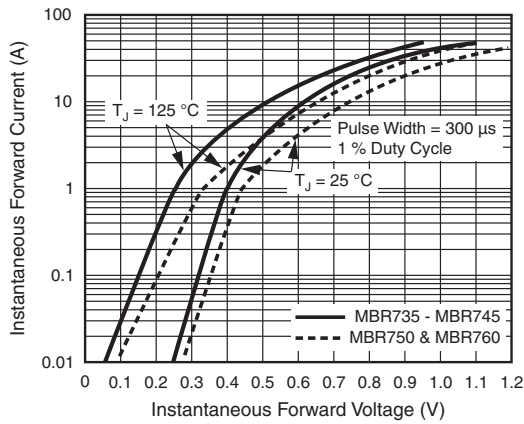


Figure 3. Typical Instantaneous Forward Characteristics

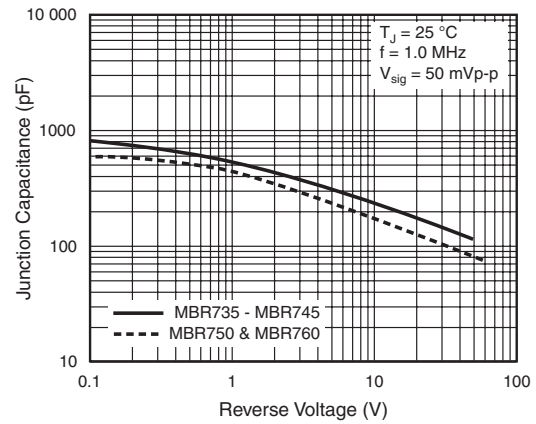


Figure 5. Typical Junction Capacitance

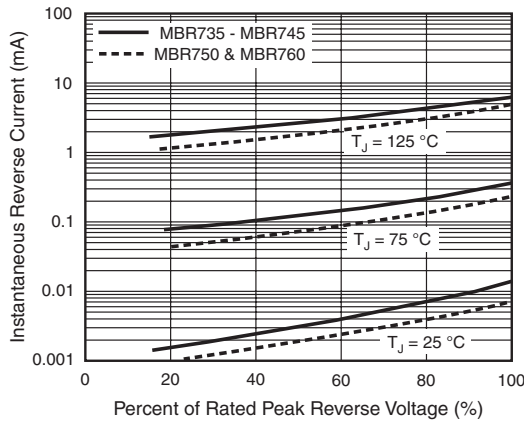


Figure 4. Typical Reverse Characteristics

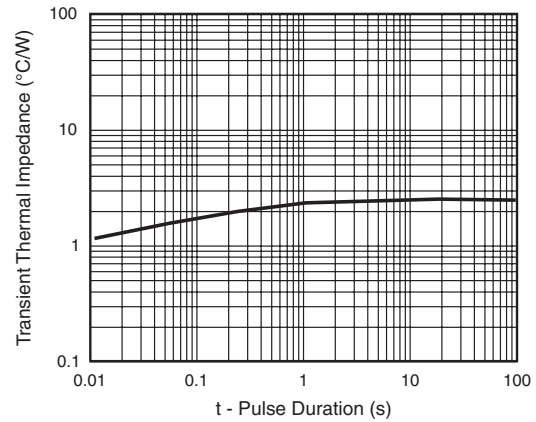


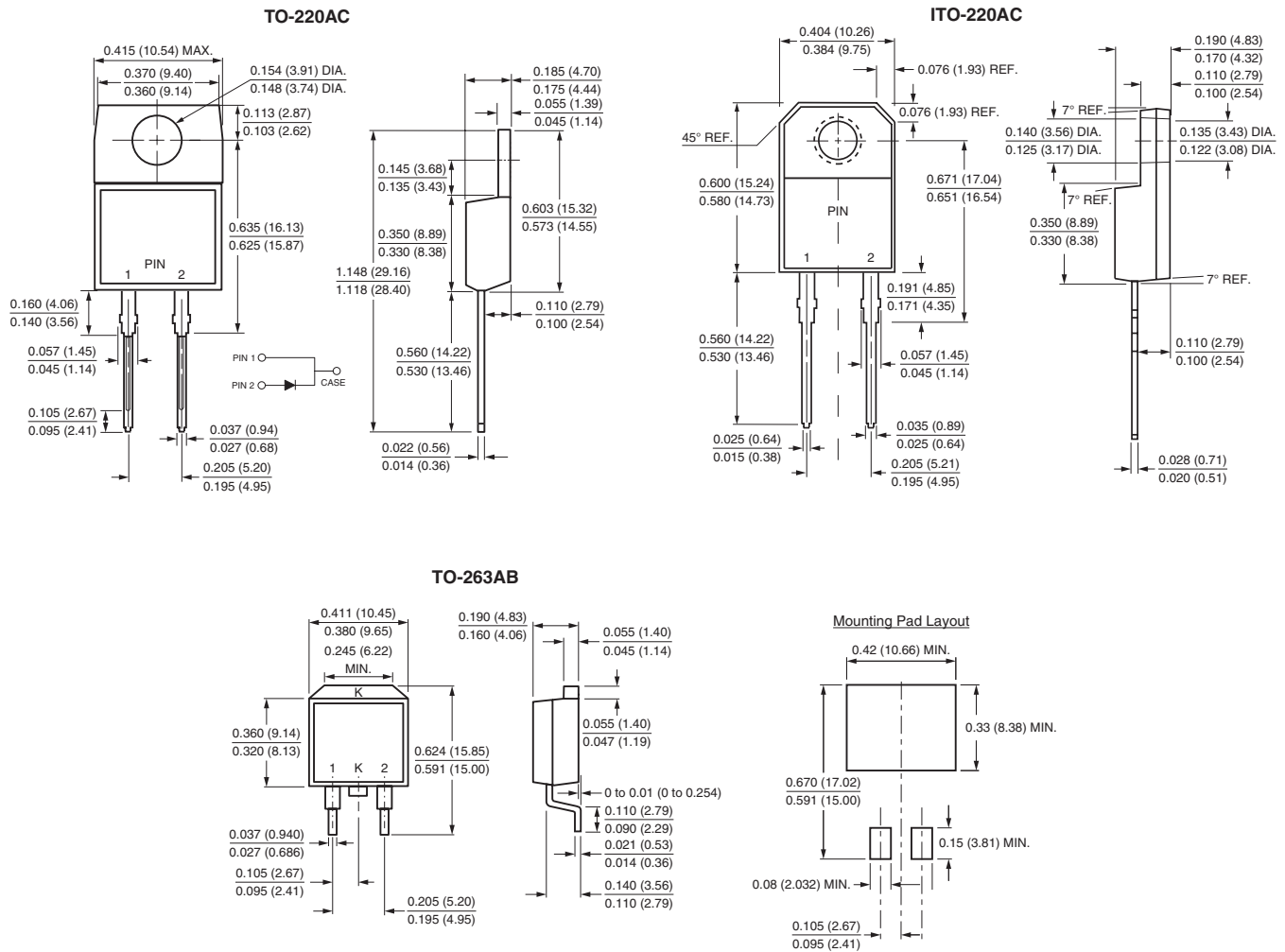
Figure 6. Typical Transient Thermal Impedance

# MBR(F,B)735 thru MBR(F,B)760

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## PACKAGE OUTLINE DIMENSIONS in inches (millimeters)



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